

LT041NS/LT041NS9

■ Features

- (1) Maximum optical power output : 60mW (CW*)
($\times 4$ CD-R writable, $\times 2$ CD-R rewritable)
 - (2) 2 series wavelength depending on the demand of customers
 - (3) Low current drive (Operating current : TYP.98mA)
 - (4) Transverse mode
 - (5) Compact $\phi 5.6$ mm package
- *CW : (Continuous Wave)

■ Model No.

- (1) LT041NS : Wavelength 780 to 795nm
- (2) LT041NS9 : Wavelength 780 to 790nm

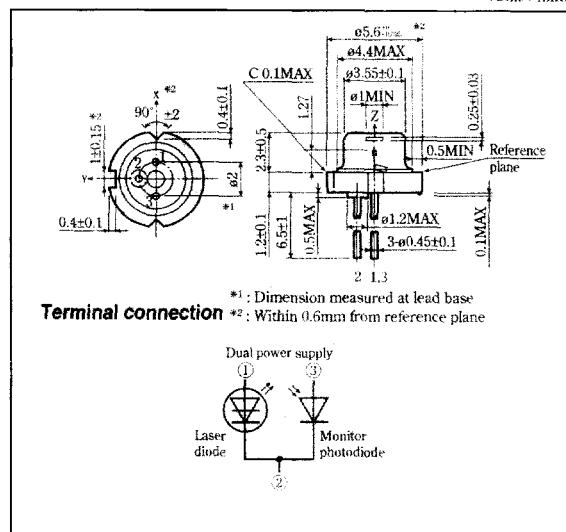
■ Applications

- (1) CD-R / CD-RW drives

High Power (Max.60mW CW), Compact Size Laser Diode for $\times 4$ Speed CD-R

■ Outline Dimensions

(Unit : mm)



*1 : Dimension measured at lead base
*2 : Within 0.6mm from reference plane

■ Absolute Maximum Ratings

(Tc=25°C)

Parameter	Symbol	Rating	Unit
Optical power output	CW	60	mW
	Pulse	*1 80	mW
Reverse voltage	V _R	2	V
*2 Operating temperature	T _{opr}	-10 to +60	°C
*2 Storage temperature	T _{stg}	-40 to +85	°C
*3 Soldering temperature	T _{sld}	260°C/5s	-

*1 Pulse width: 0.4ms, duty : 0.1%

*2 Case temperature

*3 At the position of 1.6mm or more from the lead base

■ Electro-optical Characteristics*¹

(Tc=25°C)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Threshold current	I _{th}	-		-	35	45	mA
Operating current	I _{op}	Po=50mW		-	98	128	mA
Operating voltage	V _{op}	Po=50mW		-	2.15	2.5	V
Wavelength	λ_p	Po=50mW	LT041NS	780	788	795	nm
			LT041NS9	780	-	790	
		-	-	-	-	-	-
Radiation characteristics	* ² Angle	Parallel to junction	$\theta//$	Po=50mW	8	10	13
		Perpendicular to junction	$\theta\perp$	Po=50mW	18	24	30
	Ripple	-	-	Po=50mW	-	-	±20 %
Emission point accuracy	Angle	$\Delta\theta//$	Po=50mW	-	-	±2	°
			$\Delta\theta\perp$	Po=50mW	-	-	
	Position	$\Delta x, \Delta y, \Delta z$	-	-	-	±80	μm
Differential efficiency		η	40mW I (50mW) - I (10mW)	-	0.8	-	mW/mA
Coherence		γ	Po=0 to 60mW	-	-	1.0	-
Monitor current		I _m	Po=50mW	-	0.25	-	mA

*¹ Initial value, CW drive*² Angle at 50% peak intensity(full-width at half-maximum)■ Electrical Characteristics of Photodiode
(LT041NS)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Dark current	I _d	V _R =15V	-	-	150	nA

(LT041NS9)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Dark current	I _d	V _R =15V	-	-	150	nA

• Please refer to the chapter "Handling Precautions"